

52SSF2418EB-VB Datasheet

Dual N-Channel MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)		
20	0.024 at V _{GS} = 4.5 V	6.0		
	0.028 at V _{GS} = 2.5 V	5.0		

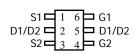
FEATURES

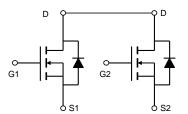
- Halogen-free Option Available
- Trench Power MOSFETs 100 % $\rm R_{\rm g}$ Tested
- Compliant to RoHS Directive 2002/95/EC



COMPLIANT







ABSOLUTE MAXIMUM RATINGS	$T_A = 25 ^{\circ}C$, unles	s otherwise n	oted			
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	20		\/	
Gate-Source Voltage		V _{GS}	± 12		V	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 25 °C	- I _D	6.0	5.2		
	T _A = 70 °C		4.8	4.2		
Pulsed Drain Current		I _{DM}	30		Α	
Continuous Source Current (Diode Conduction) ^a		I _S	1.5	1.0		
	T _A = 25 °C	В	1.5	1.0	10/	
Maximum Power Dissipation ^a	T _A = 70 °C	P _D	0.96	0.64	W	
Operating Junction and Storage Temperature Range		T _J , T _{stq}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Тур.	Max.	Unit	
Mariana haria ta Arkinda	t ≤ 10 s	R _{thJA}	72	83	°C/W	
Maximum Junction-to-Ambient ^a	Steady State		100	120		
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	55	70		

a. Surface Mounted on FR4 board, $t \le 10 \text{ s.}$

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^{*} Pb containing terminations are not RoHS compliant, exemptions may apply.



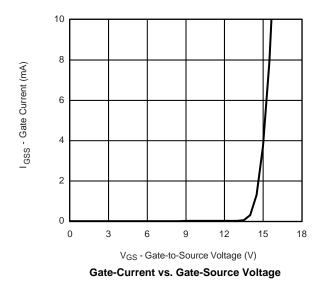
SPECIFICATIONS T _J = 25 °C, unless otherwise noted								
Parameter	Symbol	Test Conditions Min.		Typ. ^a	Max.	Unit		
Static								
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	0.5		1.5	V		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$			± 200	nA		
Zara Cata Valtaga Drain Current	1	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}$			1	μΑ		
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 20 V, V _{GS} = 0 V, T _J = 70 °C			25			
On-State Drain Current ^b	I _{D(on)}	$V_{DS} \le 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	30			Α		
5 1 2 2 2 2 1 5 1 5 b	В	$V_{GS} = 4.5 \text{ V}, I_D = 5.5 \text{ A}$		0.024		-		
Drain-Source On-State Resistance ^b	R _{DS(on)}	$V_{GS} = 2.5 \text{ V}, I_D = 3.5 \text{ A}$		0.028		Ω		
Forward Transconductance ^b	9 _{fs}	V _{DS} = 10 V, I _D = 5.5 A		30		S		
Diode Forward Voltage ^b	V_{SD}	I _S = 1.5 A, V _{GS} = 0 V		0.71	1.2	V		
Dynamic ^a								
Total Gate Charge	Q_g			12	18			
Gate-Source Charge	Q _{gs}	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 5.5 \text{ A}$		2.2		nC		
Gate-Drain Charge	Q_{gd}			3.6				
Turn-On Delay Time	t _{d(on)}			245	365			
Rise Time	t _r	V_{DD} = 10 V, R_L = 10 Ω		330	495			
Turn-Off Delay Time	t _{d(off)}	$I_D\cong 1$ A, V_{GEN} = 4.5 V, R_G = 6 Ω		860	1300	ns		
Fall Time	t _f			510	765			

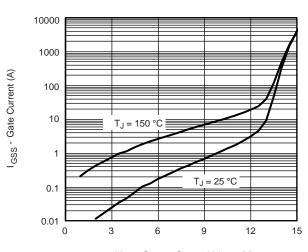
Notes:

- a. For design aid only; not subject to production testing.
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



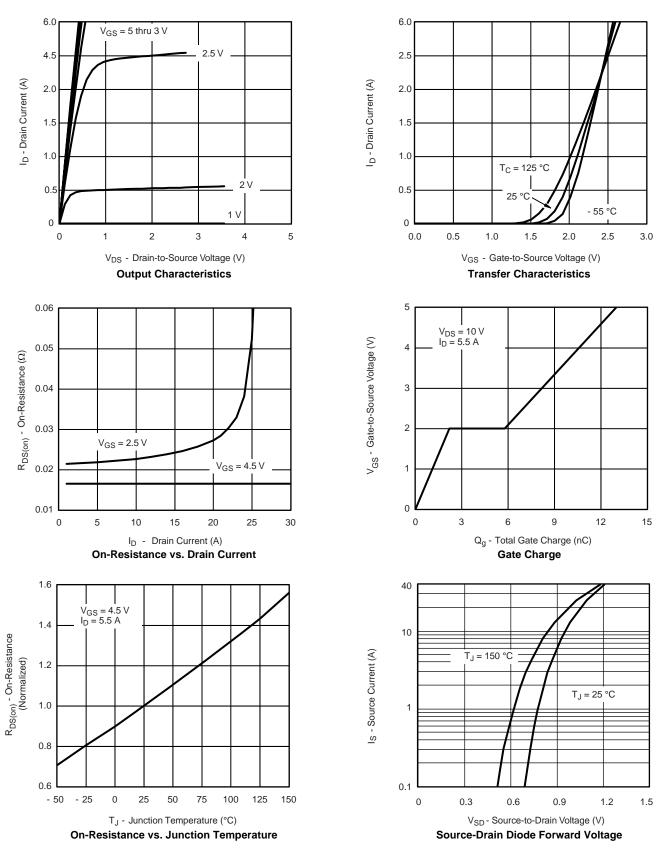


 $\label{eq:VGS} V_{GS} \text{ - Gate-to-Source Voltage (V)}$ Gate Current vs. Gate-Source Voltage

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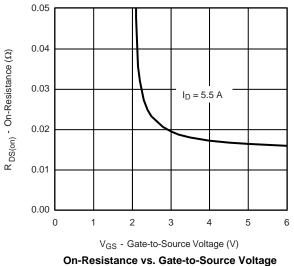


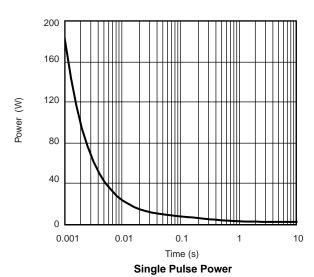
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





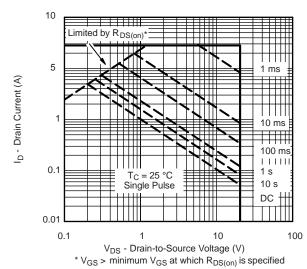
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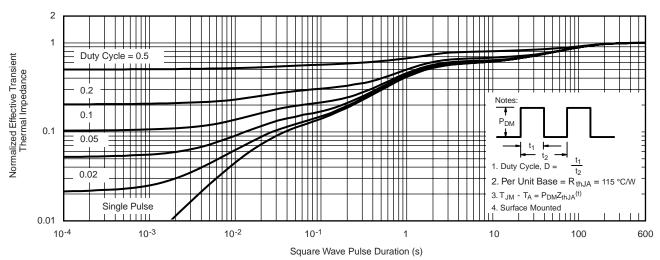


0.4 I_D = 250 μA 0.2 V_{GS(th)} Variance (V) 0.0 - 0.2 - 0.4 - 0.6 0 - 50 - 25 25 50 75 100 125 150 T_J - Temperature (°C)

Threshold Voltage



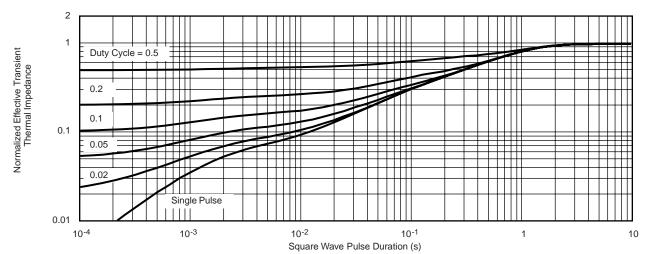
Safe Operating Area, Junction-to-Case



Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

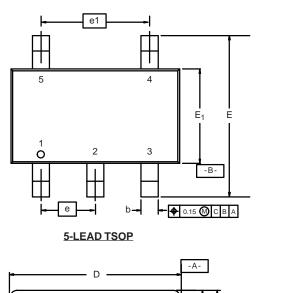


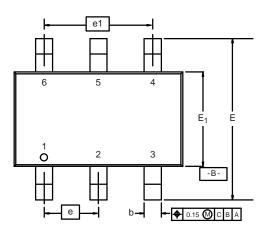
Normalized Thermal Transient Impedance, Junction-to-Foot



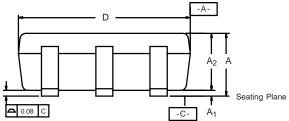
TSOP: 5/6-LEAD

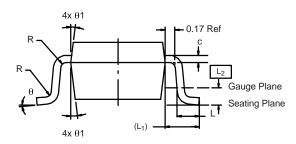
JEDEC Part Number: MO-193C





6-LEAD TSOP



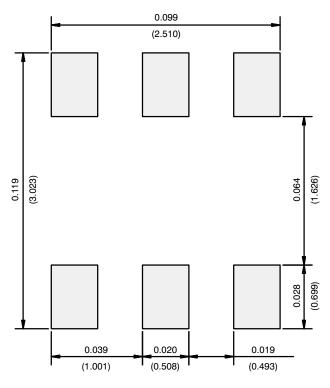


	MILLIMETERS			INCHES			
Dim	Min	Nom	Max	Min	Nom	Max	
Α	0.91	-	1.10	0.036	-	0.043	
A ₁	0.01	-	0.10	0.0004	-	0.004	
A ₂	0.90	-	1.00	0.035	0.038	0.039	
b	0.30	0.32	0.45	0.012	0.013	0.018	
С	0.10	0.15	0.20	0.004	0.006	0.008	
D	2.95	3.05	3.10	0.116	0.120	0.122	
Е	2.70	2.85	2.98	0.106	0.112	0.117	
E ₁	1.55	1.65	1.70	0.061	0.065	0.067	
е		0.95 BSC		0.0374 BSC			
e ₁	1.80	1.90	2.00	0.071 0.075 0.			
L	0.32	-	0.50	0.012	-	0.020	
L ₁	0.60 Ref			0.024 Ref			
L ₂	0.25 BSC			0.010 BSC			
R	0.10	-	-	0.004	-	-	
θ	0°	4°	8°	0°	4°	8°	
θ_1	7° Nom 7° Nom					•	
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540							

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RECOMMENDED MINIMUM PADS FOR TSOP-6



Recommended Minimum Pads Dimensions in Inches/(mm)

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